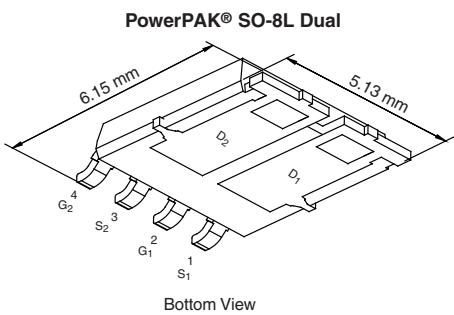


# Automotive Dual N-Channel 40 V (D-S) 175 °C MOSFET

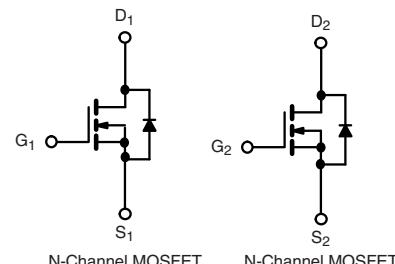
| <b>PRODUCT SUMMARY</b>                                      |        |
|---|--------|
| V <sub>DS</sub> (V)   | 40     |
| R <sub>DS(on)</sub> ( $\Omega$ ) at V <sub>GS</sub> = 10 V  | 0.0093 |
| R <sub>DS(on)</sub> ( $\Omega$ ) at V <sub>GS</sub> = 4.5 V | 0.0111 |
| I <sub>D</sub> (A) per leg                                  | 30     |
| Configuration   | Dual   |



## FEATURES

- TrenchFET® Power MOSFET
- 100 % R<sub>g</sub> and UIS Tested
- AEC-Q101 Qualified<sup>d</sup>
- Material categorization:  
For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

AUTOMOTIVE GRADE


RoHS  
COMPLIANT  
HALOGEN  
FREE


## ORDERING INFORMATION

|                                 |                  |
|---------------------------------|------------------|
| Package                         | PowerPAK SO-8L   |
| Lead (Pb)-free and Halogen-free | SQJ912AEP-T1-GE3 |

## ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = 25 °C, unless otherwise noted)

| PARAMETER  | SYMBOL                            | LIMIT         | UNIT |
|--|-----------------------------------|---------------|------|
| Drain-Source Voltage   | V <sub>DS</sub>                   | 40            | V    |
| Gate-Source Voltage  | V <sub>GS</sub>                   | ± 20          |      |
| Continuous Drain Current <sup>a</sup>                        | I <sub>D</sub>                    | 30            | A    |
|  |                                   | 29            |      |
| Continuous Source Current (Diode Conduction) <sup>a</sup>    | I <sub>S</sub>                    | 30            | A    |
| Pulsed Drain Current <sup>b</sup>                            | I <sub>DM</sub>                   | 120           |      |
| Single Pulse Avalanche Current                               | I <sub>AS</sub>                   | 26            | mJ   |
| Single Pulse Avalanche Energy                                | E <sub>AS</sub>                   | 34            |      |
| Maximum Power Dissipation <sup>b</sup>                       | P <sub>D</sub>                    | 48            | W    |
|  |                                   | 16            |      |
| Operating Junction and Storage Temperature Range             | T <sub>J</sub> , T <sub>stg</sub> | - 55 to + 175 | °C   |
| Soldering Recommendations (Peak Temperature) <sup>e, f</sup> |                                   | 260           |      |

## THERMAL RESISTANCE RATINGS

| PARAMETER                | SYMBOL            | LIMIT | UNIT |
|--------------------------|-------------------|-------|------|
| Junction-to-Ambient      | R <sub>thJA</sub> | 85    | °C/W |
| Junction-to-Case (Drain) | R <sub>thJC</sub> | 3.1   |      |

### Notes

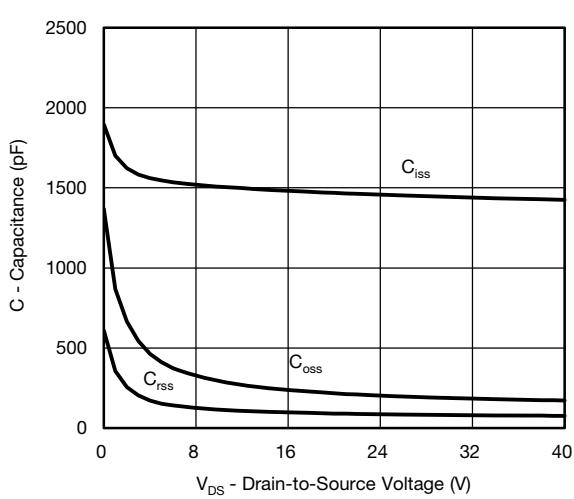
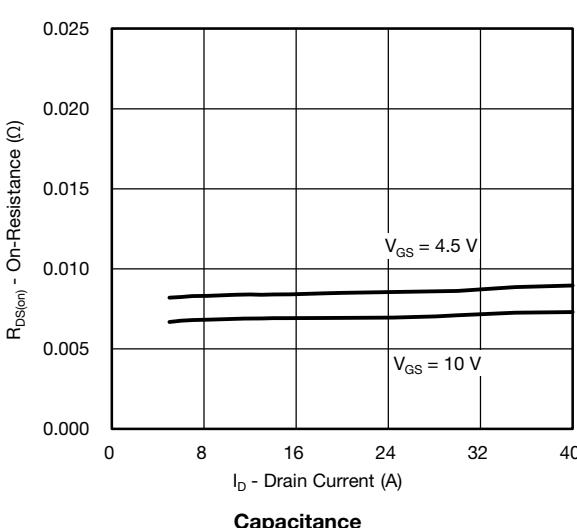
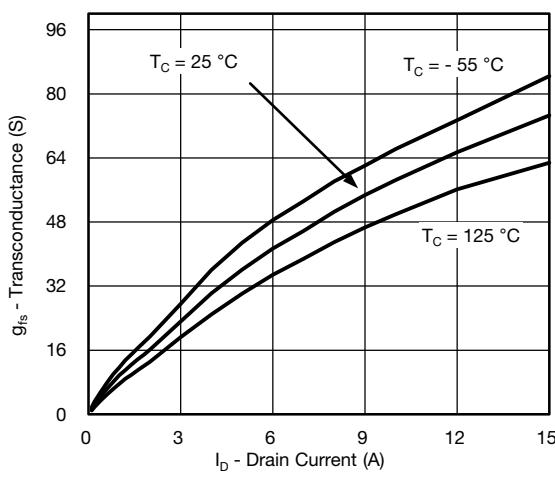
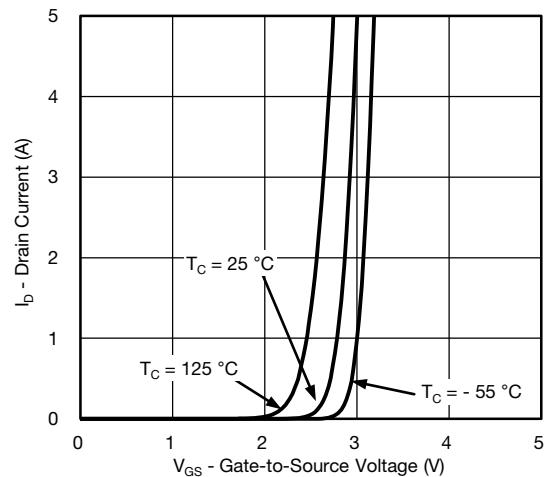
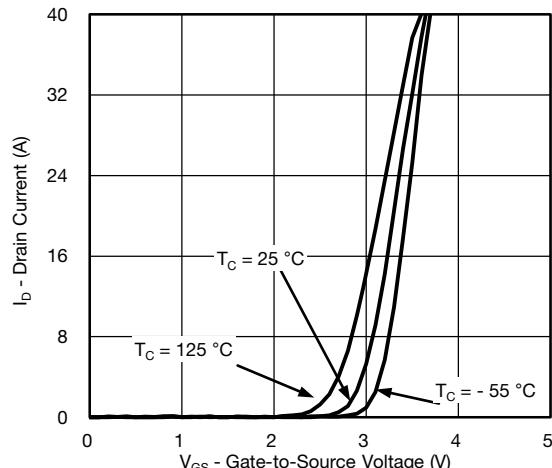
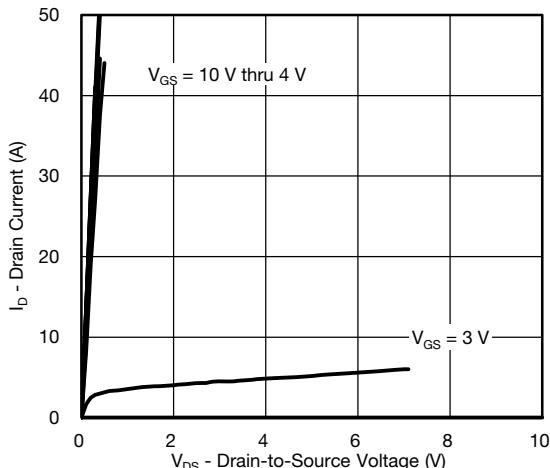
- Package limited.
- Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
- When mounted on 1" square PCB (FR4 material).
- Parametric verification ongoing.
- See solder profile ([www.vishay.com/doc?73257](http://www.vishay.com/doc?73257)). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

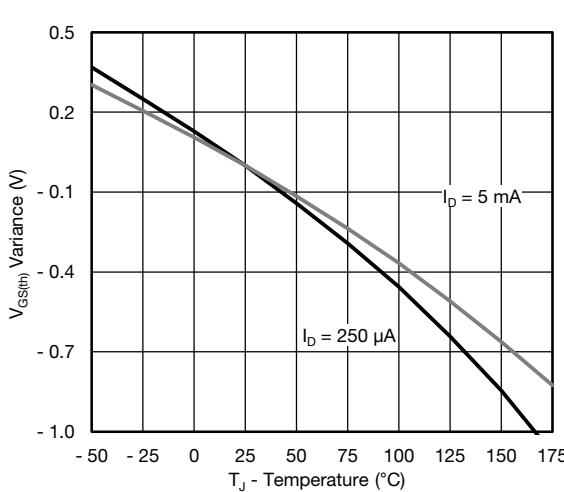
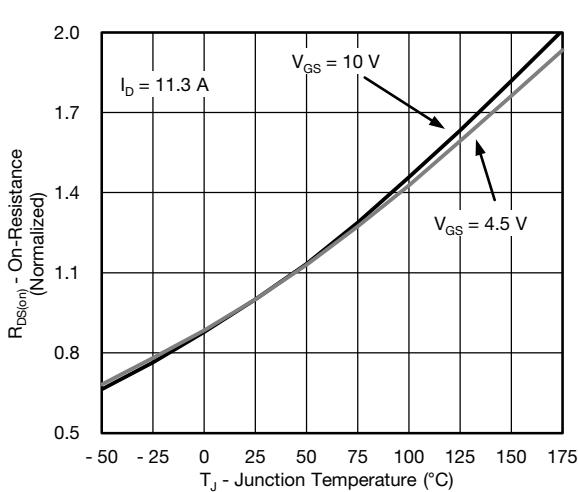
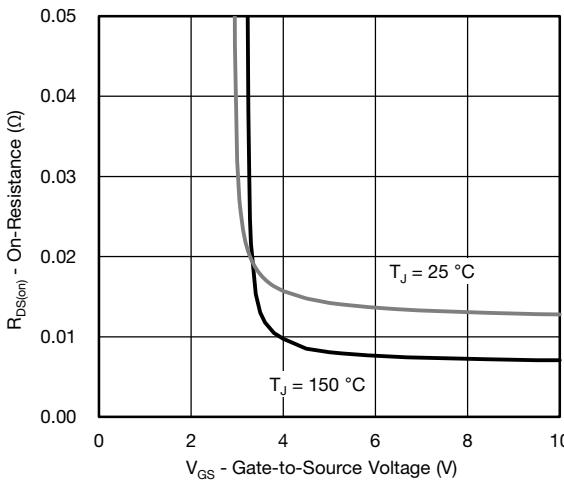
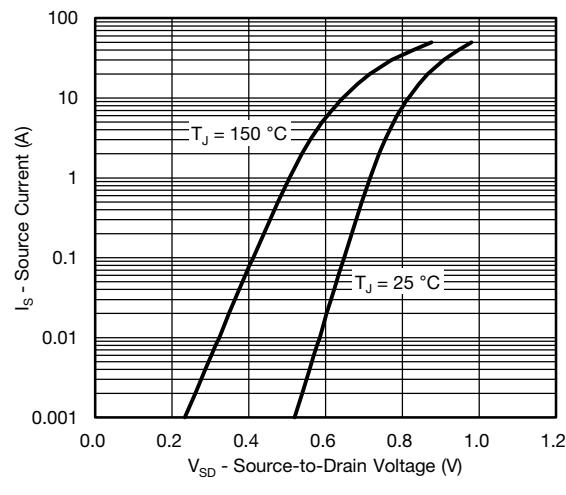
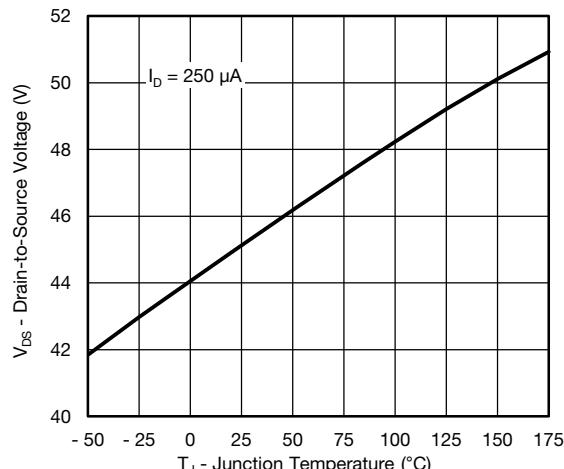
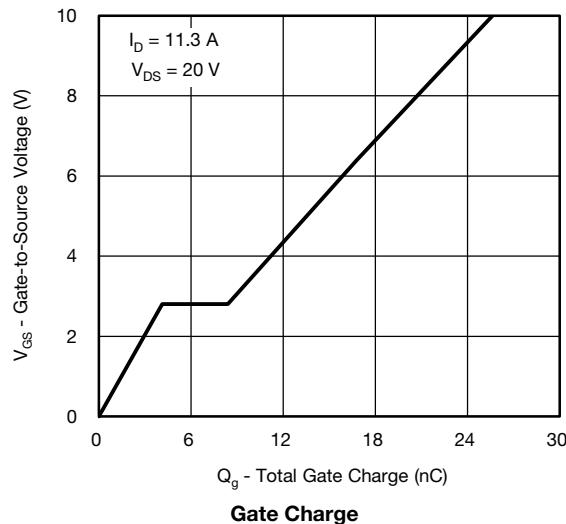
| <b>SPECIFICATIONS</b> ( $T_C = 25^\circ\text{C}$ , unless otherwise noted) |                     |   |   |      |        |           |               |  |
|--|---------------------|---|---|------|--------|-----------|---------------|--|
| PARAMETER  | SYMBOL              | TEST CONDITIONS   |   | MIN. | TYP.   | MAX.      | UNIT          |  |
| <b>Static</b>  |                     |   |   |      |        |           |               |  |
| Drain-Source Breakdown Voltage   | $V_{DS}$            | $V_{GS} = 0 \text{ V}$ , $I_D = 250 \mu\text{A}$  |   | 40   | -      | -         | V             |  |
| Gate-Source Threshold Voltage  | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}$ , $I_D = 250 \mu\text{A}$   |   | 1.5  | 2      | 2.5       |               |  |
| Gate-Source Leakage  | $I_{GSS}$           | $V_{DS} = 0 \text{ V}$ , $V_{GS} = \pm 20 \text{ V}$  |   | -    | -      | $\pm 100$ | nA            |  |
| Zero Gate Voltage Drain Current  | $I_{DSS}$           | $V_{GS} = 0 \text{ V}$  | $V_{DS} = 40 \text{ V}$                             | -    | -      | 1         | $\mu\text{A}$ |  |
|  |                     | $V_{GS} = 0 \text{ V}$  | $V_{DS} = 40 \text{ V}$ , $T_J = 125^\circ\text{C}$ | -    | -      | 50        |               |  |
|  |                     | $V_{GS} = 0 \text{ V}$  | $V_{DS} = 40 \text{ V}$ , $T_J = 175^\circ\text{C}$ | -    | -      | 150       |               |  |
| On-State Drain Current <sup>a</sup>  | $I_{D(\text{on})}$  | $V_{GS} = 10 \text{ V}$   | $V_{DS} \geq 5 \text{ V}$                           | 30   | -      | -         | A             |  |
| Drain-Source On-State Resistance <sup>a</sup>                              | $R_{DS(\text{on})}$ | $V_{GS} = 10 \text{ V}$   | $I_D = 9.7 \text{ A}$                               | -    | 0.0077 | 0.0093    | $\Omega$      |  |
|  |                     | $V_{GS} = 4.5 \text{ V}$  | $I_D = 8.9 \text{ A}$                               | -    | 0.0093 | 0.0111    |               |  |
|  |                     | $V_{GS} = 10 \text{ V}$   | $I_D = 9.7 \text{ A}$ , $T_J = 125^\circ\text{C}$   | -    | -      | 0.0138    |               |  |
|  |                     | $V_{GS} = 10 \text{ V}$   | $I_D = 9.7 \text{ A}$ , $T_J = 175^\circ\text{C}$   | -    | -      | 0.0169    |               |  |
| Forward Transconductance <sup>b</sup>                                      | $g_{fs}$            | $V_{DS} = 15 \text{ V}$ , $I_D = 10 \text{ A}$  |   | -    | 58     | -         | S             |  |
| <b>Dynamic<sup>b</sup></b>   |                     |   |   |      |        |           |               |  |
| Input Capacitance  | $C_{iss}$           | $V_{GS} = 0 \text{ V}$  | $V_{DS} = 20 \text{ V}$ , $f = 1 \text{ MHz}$       | -    | 1438   | 1835      | $\text{pF}$   |  |
| Output Capacitance   | $C_{oss}$           |   |   | -    | 217    | 271       |               |  |
| Reverse Transfer Capacitance   | $C_{rss}$           |   |   | -    | 91     | 114       |               |  |
| Total Gate Charge <sup>c</sup>   | $Q_g$               | $V_{GS} = 10 \text{ V}$   | $V_{DS} = 20 \text{ V}$ , $I_D = 11.3 \text{ A}$    | -    | 25.6   | 38        | $\text{nC}$   |  |
| Gate-Source Charge <sup>c</sup>  | $Q_{gs}$            |   |   | -    | 4      | -         |               |  |
| Gate-Drain Charge <sup>c</sup>   | $Q_{gd}$            |   |   | -    | 4      | -         |               |  |
| Gate Resistance  | $R_g$               | $f = 1 \text{ MHz}$   |   | 0.72 | 1.44   | 2.2       | $\Omega$      |  |
| Turn-On Delay Time <sup>c</sup>  | $t_{d(\text{on})}$  | $V_{DD} = 20 \text{ V}$ , $R_L = 20 \Omega$<br>$I_D \equiv 1 \text{ A}$ , $V_{GEN} = 10 \text{ V}$ , $R_g = 1 \Omega$ |   | -    | 10     | 15        | $\text{ns}$   |  |
| Rise Time <sup>c</sup>   | $t_r$               |   |   | -    | 9      | 14        |               |  |
| Turn-Off Delay Time <sup>c</sup>   | $t_{d(\text{off})}$ |   |   | -    | 23     | 35        |               |  |
| Fall Time <sup>c</sup>   | $t_f$               |   |   | -    | 11     | 17        |               |  |
| <b>Source-Drain Diode Ratings and Characteristics<sup>b</sup></b>          |                     |   |   |      |        |           |               |  |
| Pulsed Current <sup>a</sup>  | $I_{SM}$            |   |   | -    | -      | 120       | A             |  |
| Forward Voltage  | $V_{SD}$            | $I_F = 6.5 \text{ A}$ , $V_{GS} = 0 \text{ V}$  |   | -    | 0.8    | 1.1       | V             |  |

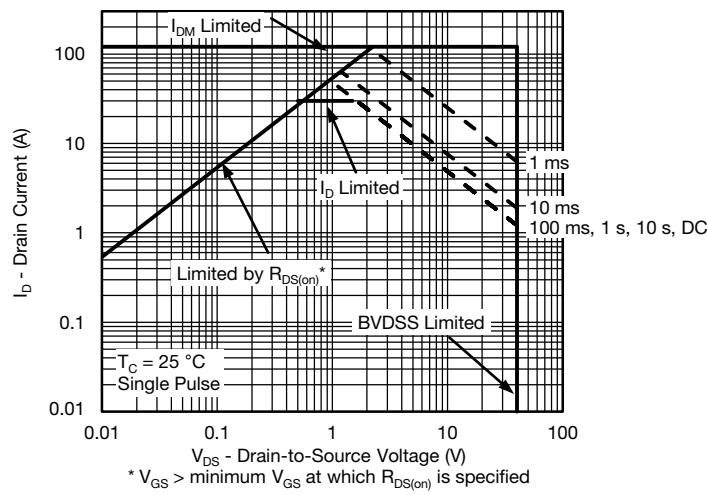
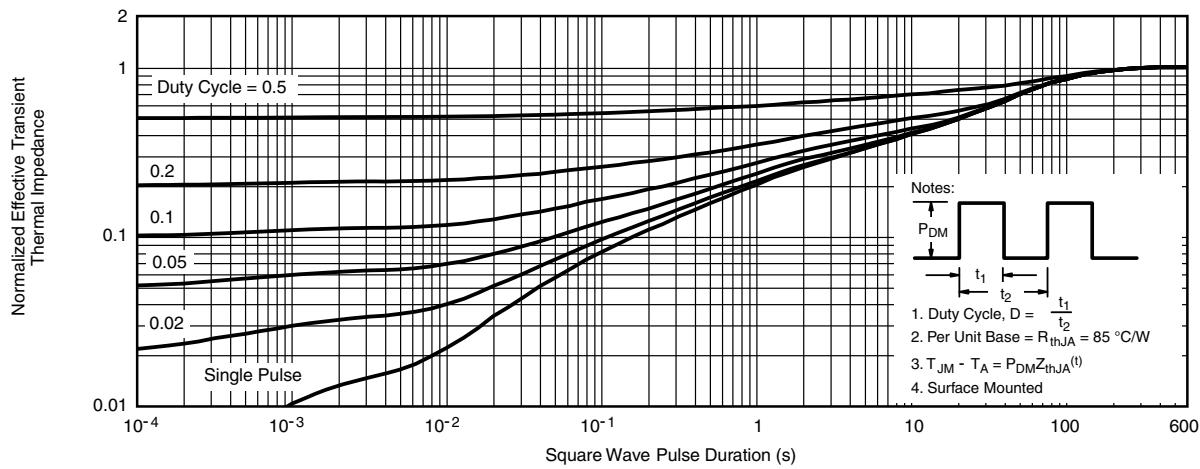
**Notes**

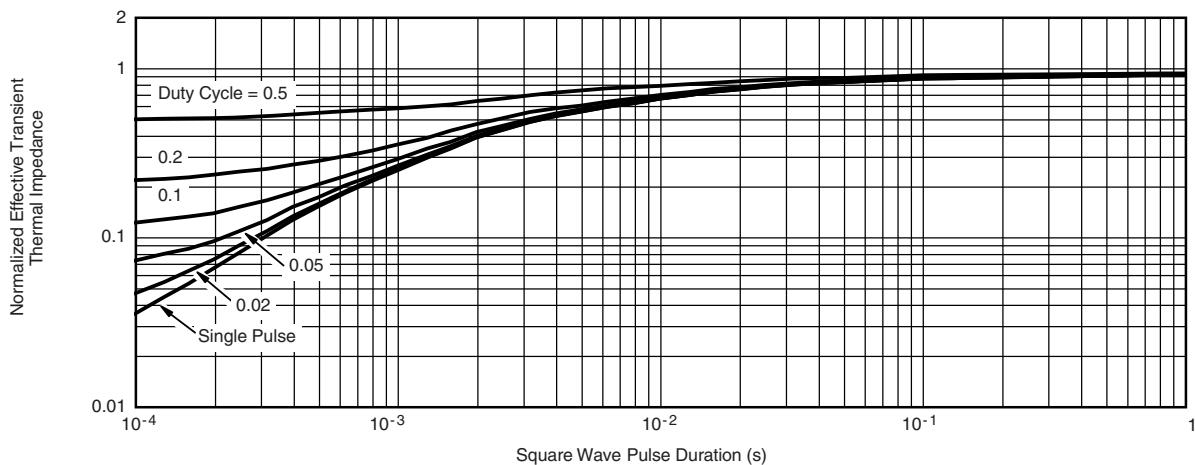
- a. Pulse test; pulse width  $\leq 300 \mu\text{s}$ , duty cycle  $\leq 2 \%$ .
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TYPICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)


**TYPICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)


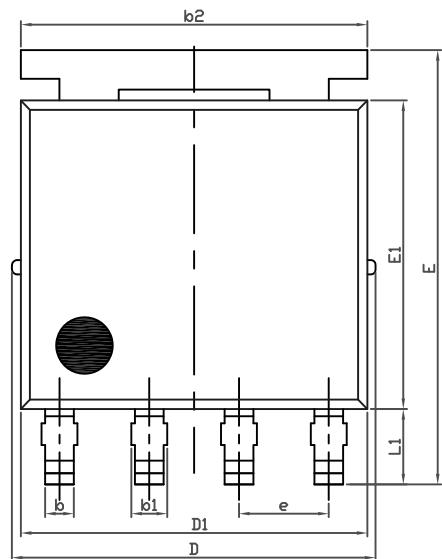
**THERMAL RATINGS** ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)

**Safe Operating Area**

**Normalized Thermal Transient Impedance, Junction-to-Ambient**

**THERMAL RATINGS** ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)

**Normalized Thermal Transient Impedance, Junction-to-Case**
**Note**

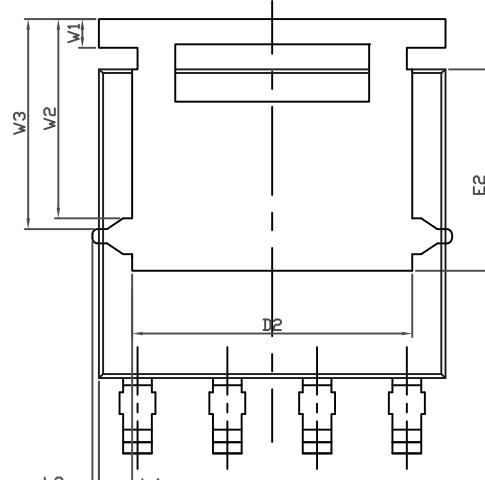
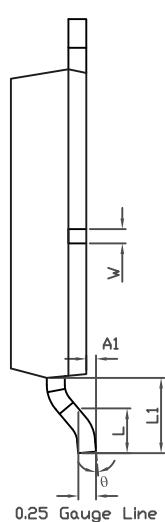
- The characteristics shown in the two graphs
    - Normalized Transient Thermal Impedance Junction-to-Ambient ( $25^\circ\text{C}$ )
    - Normalized Transient Thermal Impedance Junction-to-Case ( $25^\circ\text{C}$ )
- are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see [www.vishay.com/ppg?62876](http://www.vishay.com/ppg?62876).

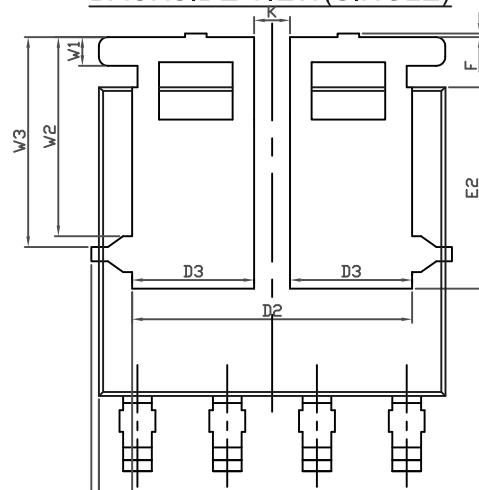
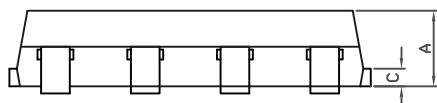
## PowerPAK® SO-8L Case Outline



TOPSIDE VIEW



BACKSIDE VIEW(SINGLE)



BACKSIDE VIEW(DUAL)



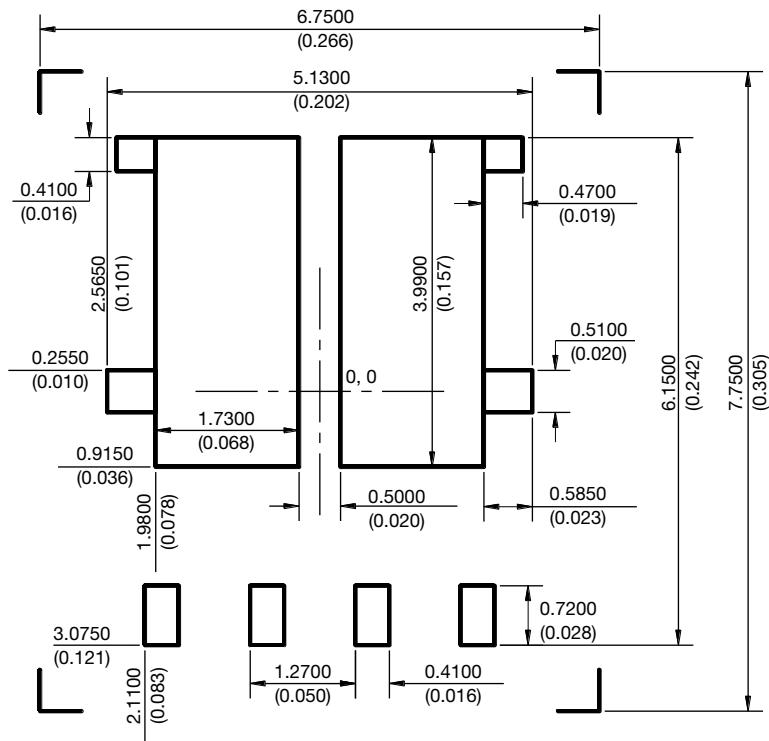
| DIM.                   | MILLIMETERS |      |       | INCHES    |       |       |
|------------------------|-------------|------|-------|-----------|-------|-------|
|                        | MIN.        | NOM. | MAX.  | MIN.      | NOM.  | MAX.  |
| A                      | 1.00        | 1.07 | 1.14  | 0.039     | 0.042 | 0.045 |
| A1                     | 0.00        | -    | 0.127 | 0.00      | -     | 0.005 |
| b                      | 0.33        | 0.41 | 0.48  | 0.013     | 0.016 | 0.019 |
| b1                     | 0.44        | 0.51 | 0.58  | 0.017     | 0.020 | 0.023 |
| b2                     | 4.80        | 4.90 | 5.00  | 0.189     | 0.193 | 0.197 |
| b3                     | 0.094       |      |       | 0.004     |       |       |
| b4                     | 0.47        |      |       | 0.019     |       |       |
| c                      | 0.20        | 0.25 | 0.30  | 0.008     | 0.010 | 0.012 |
| D                      | 5.00        | 5.13 | 5.25  | 0.197     | 0.202 | 0.207 |
| D1                     | 4.80        | 4.90 | 5.00  | 0.189     | 0.193 | 0.197 |
| D2                     | 3.86        | 3.96 | 4.06  | 0.152     | 0.156 | 0.160 |
| D3                     | 1.63        | 1.73 | 1.83  | 0.064     | 0.068 | 0.072 |
| e                      | 1.27 BSC    |      |       | 0.050 BSC |       |       |
| E                      | 6.05        | 6.15 | 6.25  | 0.238     | 0.242 | 0.246 |
| E1                     | 4.27        | 4.37 | 4.47  | 0.168     | 0.172 | 0.176 |
| E2 (for AI product)    | 2.75        | 2.85 | 2.95  | 0.108     | 0.112 | 0.116 |
| E2 (for other product) | 3.18        | 3.28 | 3.38  | 0.125     | 0.129 | 0.133 |
| F                      | -           | -    | 0.15  | -         | -     | 0.006 |
| L                      | 0.62        | 0.72 | 0.82  | 0.024     | 0.028 | 0.032 |
| L1                     | 0.92        | 1.07 | 1.22  | 0.036     | 0.042 | 0.048 |
| K                      | 0.51        |      |       | 0.020     |       |       |
| W                      | 0.23        |      |       | 0.009     |       |       |
| W1                     | 0.41        |      |       | 0.016     |       |       |
| W2                     | 2.82        |      |       | 0.111     |       |       |
| W3                     | 2.96        |      |       | 0.117     |       |       |
| θ                      | 0°          | -    | 10°   | 0°        | -     | 10°   |

ECN: C12-0026-Rev. B, 27-Aug-12

DWG: 5976

**Note**

- Millimeters will gover

**RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L DUAL**


Recommended Minimum Pads  
Dimensions in mm (inches)  
Keep-out 6.75 (0.266) x 7.75 (0.305)



### Disclaimer

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**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.**



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#### Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помошь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помошь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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Факс: 8 (812) 320-02-42

Электронная почта: [org@eplast1.ru](mailto:org@eplast1.ru)

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.